

NLSV8T240

8-Bit Dual-Supply Inverting Level Translator

The NLSV8T240 is a 8-bit configurable dual-supply voltage level translator. The input A_n and output B_n ports are designed to track two different power supply rails, V_{CCA} and V_{CCB} respectively. Both supply rails are configurable from 0.9 V to 4.5 V allowing universal low-voltage translation from the input A_n to the output B_n port.

Features

- Wide V_{CCA} and V_{CCB} Operating Range: 0.9 V to 4.5 V
- High-Speed w/ Balanced Propagation Delay
- Inputs and Outputs have OVT Protection to 4.5 V
- Non-preferential V_{CCA} and V_{CCB} Sequencing
- Outputs at 3-State until Active V_{CC} is Reached
- Power-Off Protection
- Outputs Switch to 3-State with V_{CCB} at GND
- Ultra-Small Packaging: 4.0 mm x 2.0 mm UDFN20
- This is a Pb-Free Device

Typical Applications

- Mobile Phones, PDAs, Other Portable Devices

Important Information

- ESD Protection for All Pins:
HBM (Human Body Model) > 7000 V

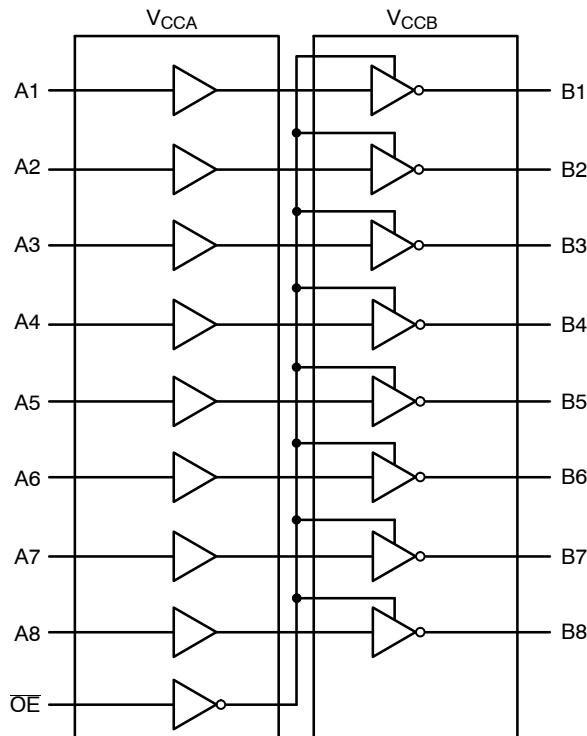


Figure 1. Logic Diagram



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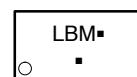


UDFN20
MU SUFFIX
CASE 517AK

LB = Specific Device Code
M = Date Code
▪ = Pb-Free Package

(Note: Microdot may be in either location)

MARKING DIAGRAM



PIN ASSIGNMENT

V_{CCA}	1	20	V_{CCB}
A1	2	19	B1
A2	3	18	B2
A3	4	17	B3
A4	5	16	B4
A5	6	15	B5
A6	7	14	B6
A7	8	13	B7
A8	9	12	B8
GND	10	11	OE

(Top View)

ORDERING INFORMATION

Device	Package	Shipping [†]
NLSV8T240MUTAG	UDFN20 (Pb-Free)	3000/Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

NLSV8T240

PIN ASSIGNMENT

PIN	FUNCTION
V _{CCA}	Input Port DC Power Supply
V _{CCB}	Output Port DC Power Supply
GND	Ground
A _n	Input Port
B _n	Output Port
OE	Output Enable

TRUTH TABLE

Inputs		Outputs
OE	A _n	B _n
L	L	H
L	H	L
H	X	3-State

MAXIMUM RATINGS

Symbol	Rating	Value	Condition	Unit
V _{CCA} , V _{CCB}	DC Supply Voltage	-0.5 to +5.5		V
V _I	DC Input Voltage	A _n	-0.5 to +5.5	V
V _C	Control Input	OE	-0.5 to +5.5	V
V _O	DC Output Voltage (Power Down)	B _n	-0.5 to +5.5	V _{CCA} = V _{CCB} = 0
	(Active Mode)	B _n	-0.5 to +5.5	V
	(Tri-State Mode)	B _n	-0.5 to +5.5	V
I _{IK}	DC Input Diode Current		-20	VI < GND
I _{OK}	DC Output Diode Current		-50	VO < GND
I _O	DC Output Source/Sink Current		±50	mA
I _{CCA} , I _{CCB}	DC Supply Current Per Supply Pin		±100	mA
I _{GND}	DC Ground Current per Ground Pin		±100	mA
T _{STG}	Storage Temperature		-65 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit
V _{CCA} , V _{CCB}	Positive DC Supply Voltage	0.9	4.5	V
V _I	Bus Input Voltage	GND	4.5	V
V _C	Control Input	OE	GND	V
V _{IO}	Bus Output Voltage (Power Down Mode)	B _n	GND	V
	(Active Mode)	B _n	GND	V _{CCB}
	(Tri-State Mode)	B _n	GND	V
T _A	Operating Temperature Range	-40	+85	°C
Δt / ΔV	Input Transition Rise or Rate V _I , from 30% to 70% of V _{CC} ; V _{CC} = 3.3 V ±0.3 V	0	10	nS

DC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Test Conditions	V_{CCA} (V)	V_{CCB} (V)	-40°C to +85°C		Unit
					Min	Max	
V_{IH}	Input HIGH Voltage (An, \overline{OE})		3.6 – 4.5	0.9 – 4.5	2.2	–	V
			2.7 – 3.6		2.0	–	
			2.3 – 2.7		1.6	–	
			1.4 – 2.3		0.65 * V_{CCA}	–	
			0.9 – 1.4		0.9 * V_{CCA}	–	
V_{IL}	Input LOW Voltage (An, \overline{OE})		3.6 – 4.5	0.9 – 4.5	–	0.8	V
			2.7 – 3.6		–	0.8	
			2.3 – 2.7		–	0.7	
			1.4 – 2.3		–	0.35 * V_{CCA}	
			0.9 – 1.4		–	0.1 * V_{CCA}	
V_{OH}	Output HIGH Voltage	$I_{OH} = -100 \mu A; V_I = V_{IL}$	0.9 – 4.5	0.9 – 4.5	$V_{CCB} - 0.2$	–	V
			$I_{OH} = -0.5 \text{ mA}; V_I = V_{IL}$	0.9	0.9	0.75 * V_{CCB}	
			$I_{OH} = -2 \text{ mA}; V_I = V_{IL}$	1.4	1.4	1.05	
			$I_{OH} = -6 \text{ mA}; V_I = V_{IL}$	1.65	1.65	1.25	
			2.3	2.3	2.0	–	
			$I_{OH} = -12 \text{ mA}; V_I = V_{IL}$	2.3	2.3	1.8	
			2.7	2.7	2.2	–	
			$I_{OH} = -18 \text{ mA}; V_I = V_{IL}$	2.3	2.3	1.7	–
			3.0	3.0	2.4	–	
			$I_{OH} = -24 \text{ mA}; V_I = V_{IL}$	3.0	3.0	2.2	–
V_{OL}	Output LOW Voltage	$I_{OL} = 100 \mu A; V_I = V_{IH}$	0.9 – 4.5	0.9 – 4.5	–	0.2	V
			$I_{OL} = 0.5 \text{ mA}; V_I = V_{IH}$	1.1	1.1	–	
			$I_{OL} = 2 \text{ mA}; V_I = V_{IH}$	1.4	1.4	–	
			$I_{OL} = 6 \text{ mA}; V_I = V_{IH}$	1.65	1.65	–	
			$I_{OL} = 12 \text{ mA}; V_I = V_{IH}$	2.3	2.3	–	
			2.7	2.7	–	0.4	
			$I_{OL} = 18 \text{ mA}; V_I = V_{IH}$	2.3	2.3	–	
			3.0	3.0	–	0.6	
			$I_{OL} = 24 \text{ mA}; V_I = V_{IH}$	3.0	3.0	–	0.4
			3.0	3.0	–	0.55	
I_I	Input Leakage Current	$V_I = V_{CCA}$ or GND	0.9 – 4.5	0.9 – 4.5	-1.0	1.0	μA
I_{OFF}	Power-Off Leakage Current	$\overline{OE} = 0 \text{ V}$	0 0.9 – 4.5	0.9 – 4.5 0	-1.0 -1.0	1.0 1.0	μA
I_{CCA}	Quiescent Supply Current	$V_I = V_{CCA}$ or GND; $I_O = 0$, $V_{CCA} = V_{CCB}$	0.9 – 4.5	0.9 – 4.5	–	2.0	μA
I_{CCB}	Quiescent Supply Current	$V_I = V_{CCA}$ or GND; $I_O = 0$, $V_{CCA} = V_{CCB}$	0.9 – 4.5	0.9 – 4.5	–	2.0	μA
$I_{CCA} + I_{CCB}$	Quiescent Supply Current	$V_I = V_{CCA}$ or GND; $I_O = 0$, $V_{CCA} = V_{CCB}$	0.9 – 4.5	0.9 – 4.5	–	4.0	μA
ΔI_{CCA}	Increase in I_{CC} per Input Voltage, Other Inputs at V_{CCA} or GND	$V_I = V_{CCA} - 0.6 \text{ V}$; $V_I = V_{CCA}$ or GND	4.5 3.6	4.5 3.6	–	10 5.0	μA
ΔI_{CCB}	Increase in I_{CC} per Input Voltage, Other Inputs at V_{CCA} or GND	$V_I = V_{CCA} - 0.6 \text{ V}$; $V_I = V_{CCA}$ or GND	4.5 3.6	4.5 3.6	–	10 5.0	μA
I_{OZ}	I/O Tri-State Output Leakage Current	$T_A = 25^\circ\text{C}$, $\overline{OE} = 0 \text{ V}$	0.9 – 4.5	0.9 – 4.5	-1.0	1.0	μA

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TOTAL STATIC POWER CONSUMPTION ($I_{CCA} + I_{CCB}$)

V_{CCA} (V)	-40°C to +85°C										Unit	
	V_{CCB} (V)											
	4.5		3.3		2.8		1.8		0.9			
	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max		
4.5		2		2		2		2		< 1.5	µA	
3.3		2		2		2		2		< 1.5	µA	
2.8		< 2		< 1		< 1		< 0.5		< 0.5	µA	
1.8		< 1		< 1		< 0.5		< 0.5		< 0.5	µA	
0.9		< 0.5		< 0.5		< 0.5		< 0.5		< 0.5	µA	

NOTE: Connect ground before applying supply voltage V_{CCA} or V_{CCB} . This device is designed with the feature that the power-up sequence of V_{CCA} and V_{CCB} will not damage the IC.

AC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	V_{CCA} (V)	-40°C to +85°C										Unit	
			V_{CCB} (V)											
			4.5		3.3		2.8		1.8		1.2			
			Min	Max	Min	Max	Min	Max	Min	Max	Min	Max		
t_{PLH}, t_{PHL} (Note 1)	Propagation Delay, A_n to B_n	4.5		1.6		1.8		2.0		2.1		2.3	nS	
		3.3		1.7		1.9		2.1		2.3		2.6		
		2.8		1.9		2.1		2.3		2.5		2.8		
		1.8		2.1		2.4		2.5		2.7		3.0		
		1.2		2.4		2.7		2.8		3.0		3.3		
t_{PZH}, t_{PZL} (Note 1)	Output Enable, \overline{OE} to B_n	4.5		2.6		3.8		4.0		4.1		4.3	nS	
		3.3		3.7		3.9		4.1		4.3		4.6		
		2.5		3.9		4.1		4.3		4.5		4.8		
		1.8		4.1		4.4		4.5		4.7		5.0		
		1.2		4.4		4.7		4.8		5.0		5.3		
t_{PHZ}, t_{PLZ} (Note 1)	Output Disable, \overline{OE} to B_n	4.5		2.6		3.8		4.0		4.1		4.3	nS	
		3.3		3.7		3.9		4.1		4.3		4.6		
		2.5		3.9		4.1		4.3		4.5		4.8		
		1.8		4.1		4.4		4.5		4.7		5.0		
		1.2		4.4		4.7		4.8		5.0		5.3		
t_{OSHL}, t_{OSLH} (Note 1)	Output to Output Skew, Time	4.5		0.15		0.15		0.15		0.15		0.15	nS	
		3.3		0.15		0.15		0.15		0.15		0.15		
		2.5		0.15		0.15		0.15		0.15		0.15		
		1.8		0.15		0.15		0.15		0.15		0.15		
		1.2		0.15		0.15		0.15		0.15		0.15		

1. Propagation delays defined per Figure 2.

CAPACITANCE

Symbol	Parameter	Test Conditions	Typ (Note 2)	Unit
C_{IN}	Control Pin Input Capacitance	$V_{CCA} = V_{CCB} = 3.3$ V, $V_I = 0$ V or $V_{CCA/B}$	3.5	pF
$C_{I/O}$	I/O Pin Input Capacitance	$V_{CCA} = V_{CCB} = 3.3$ V, $V_I = 0$ V or $V_{CCA/B}$	5.0	pF
C_{PD}	Power Dissipation Capacitance	$V_{CCA} = V_{CCB} = 3.3$ V, $V_I = 0$ V or V_{CCA} , $f = 10$ MHz	20	pF

2. Typical values are at $T_A = +25^\circ\text{C}$.

3. C_{PD} is defined as the value of the IC's equivalent capacitance from which the operating current can be calculated from:

$$I_{CC(\text{operating})} \cong C_{PD} \times V_{CC} \times f_{IN} \times N_{SW} \text{ where } I_{CC} = I_{CCA} + I_{CCB} \text{ and } N_{SW} = \text{total number of outputs switching.}$$

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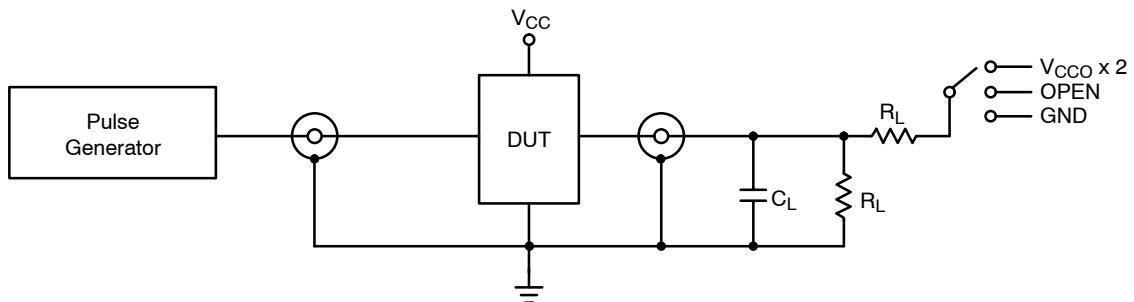


Figure 2. AC (Propagation Delay) Test Circuit

Test	Switch
t_{PLH}, t_{PHL}	OPEN
t_{PLZ}, t_{PZL}	$V_{CCO} \times 2$
t_{PHZ}, t_{PZH}	GND

$C_L = 15 \text{ pF}$ or equivalent (includes probe and jig capacitance)
 $R_L = 2 \text{ k}\Omega$ or equivalent
 Z_{OUT} of pulse generator = 50Ω

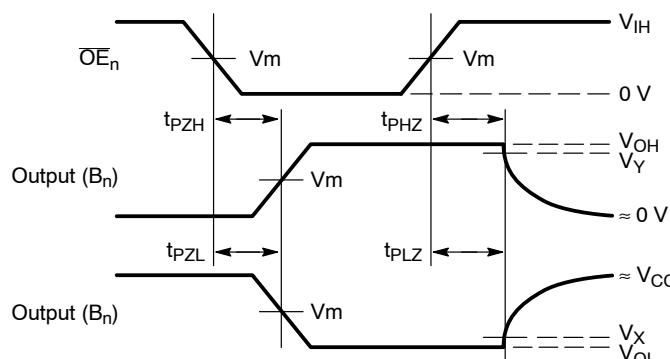
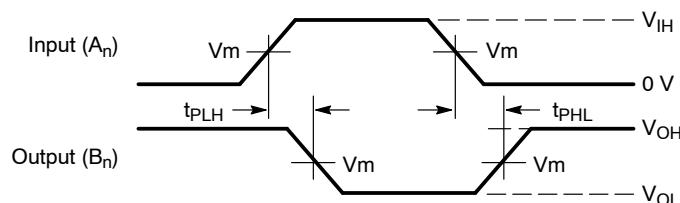
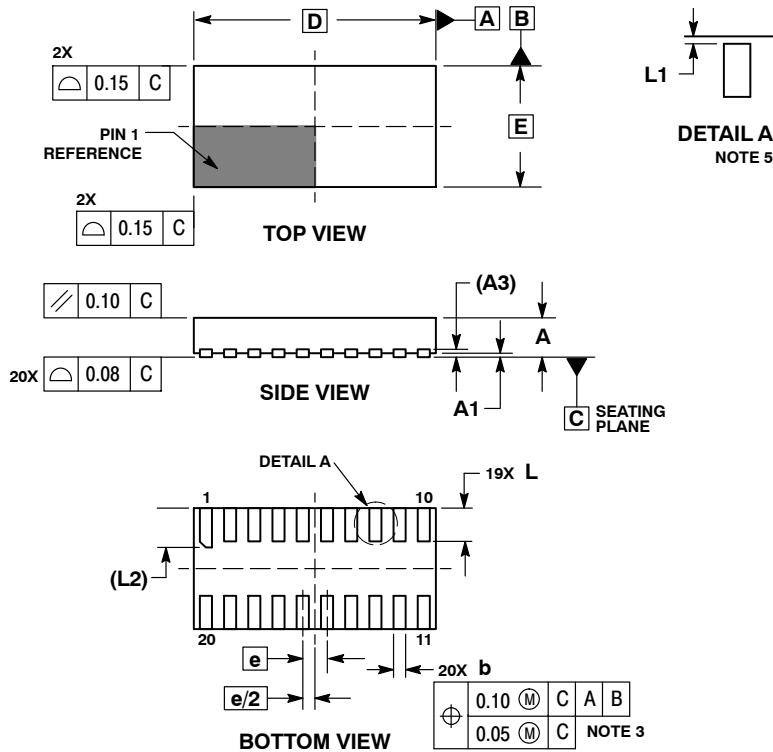


Figure 3. AC (Propagation Delay) Test Circuit Waveforms

Symbol	V_{CC}				
	3.0 V – 4.5 V	2.3 V – 2.7 V	1.65 V – 1.95 V	1.4 V – 1.6 V	0.9 V – 1.3 V
V_{mA}	$V_{CCA}/2$	$V_{CCA}/2$	$V_{CCA}/2$	$V_{CCA}/2$	$V_{CCA}/2$
V_{mB}	$V_{CCB}/2$	$V_{CCB}/2$	$V_{CCB}/2$	$V_{CCB}/2$	$V_{CCB}/2$
V_X	$V_{OL} \times 0.1$				
V_Y	$V_{OH} \times 0.9$				

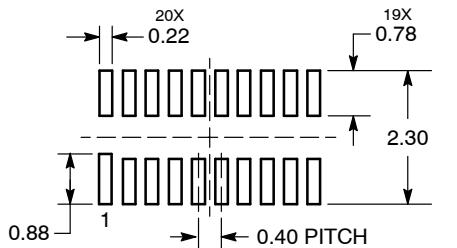
PACKAGE DIMENSIONS

UDFN20 4x2, 0.4P
CASE 517AK
ISSUE O

NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSIONS b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.30 MM FROM TERMINAL TIP.
4. MOLD FLASH ALLOWED ON TERMINALS ALONG EDGE OF PACKAGE. FLASH MAY NOT EXCEED 0.03 ONTO BOTTOM SURFACE OF TERMINALS.
5. DETAIL A SHOWS OPTIONAL CONSTRUCTION FOR TERMINALS.

MILLIMETERS		
DIM	MIN	MAX
A	0.45	0.55
A1	0.00	0.05
A3	0.13 REF	
b	0.15	0.25
D	4.00 BSC	
E	2.00 BSC	
e	0.40 BSC	
L	0.50	0.60
L1	0.00	0.03
L2	0.60	0.70

MOUNTING FOOTPRINT
SOLDERMASK DEFINED

DIMENSIONS: MILLIMETERS

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